

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L2	14115	programm\$3 same EEPROM	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/22 08:24
L3	211	2 same transistor same (P\$1type or P\$1well or P\$1channel)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/22 08:28
L4	146	3 same (N\$1well or N\$1type or N\$1channel)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/22 08:28
L5	33	4 and 365/185.18,185.01,185.26, 226.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/22 08:26
L6	18	4 and 365/185.18.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/22 08:27
L7	2	4 same (first adj3 voltage) same (second adj3 voltage)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/22 08:27
L8	40	4 and (first adj3 voltage) and (second adj3 voltage)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/22 08:27
L10	33	8 and "365"/\$7.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/22 08:28

L11	2926	2 and transistor and (P\$1type or P\$1well or P\$1channel)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/22 08:28
L12	64	11 and (N\$1well or N\$1type or N\$1channel) and (first adj3 positive adj3 voltage) and (second adj3 positive adj3 voltage)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/22 08:29
L13	30	12 and (first adj3 negative adj3 voltage)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/22 08:29
L14	26	13 and "365"/\$7.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/22 08:30
L15	16	14 and current and bias	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/22 08:30
L18	0	(programm\$3 and EEPROM and transistor and (P\$1well or P\$1type) and (N\$1well or N\$1type) and (first adj3 voltage) and (second adj3 voltage) and bit\$1line and current and bias and electron).CLM.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/22 08:32
L19	93	chen-chen.in.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/22 08:32
L20	0	chen-chen-c.in.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/22 08:32

L21	174	chen-chen-\$.in.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/22 08:32
L22	1	huang-shui.in.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/22 08:33
L24	0	huang-shui-c.in.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/22 08:33
L25	17	huang-shui-\$.in.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/22 08:33
L26	18	365/185.18 and EEPROM and (first adj3 positive adj3 voltage) and (second adj3 positive adj3 voltage) and (first adj3 negative adj3 voltage)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/22 08:34
L28	8	26 and current and electron and bias	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/22 08:36